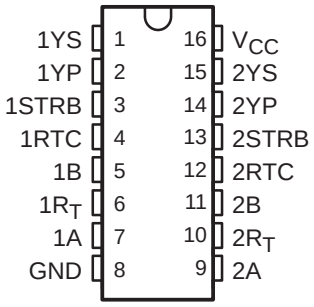
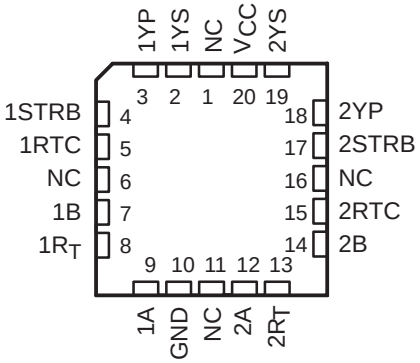
- **Choice of Open-Collector or Active Pullup (Totem-Pole) Outputs**
- **Single 5-V Supply**
- **Differential Line Operation**
- **Dual-Channel Operation**
- **TTL Compatible**
- **±15-V Common-Mode Input Voltage Range**
- **Optional-Use Built-In 130-Ω Line-Terminating Resistor**
- **Individual Frequency-Response Controls**
- **Individual Channel Strobes**
- **Designed for Use With SN55113, SN75113, SN55114, and SN75114 Drivers**
- **Designed to Be Interchangeable With National DS9615 Line Receivers**

SN55115 . . . J OR W PACKAGE
SN75115 . . . N PACKAGE
(TOP VIEW)



SN55114 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

description

The SN55115 and SN75115 dual differential line receivers are designed to sense small differential signals in the presence of large common-mode noise. These devices give TTL-compatible output signals as a function of the differential input voltage. The open-collector output configuration permits the wire-ANDing of similar TTL outputs (such as SN5401/SN7401) or other SN55115/SN75115 line receivers. This permits a level of logic to be implemented without extra delay.

The output stages are similar to TTL totem-pole outputs, but with sink outputs, 1YS and 2YS, and the corresponding active pullup terminals, 1YP and 2YP, available on adjacent package pins. The frequency response and noise immunity may be provided by a single external capacitor. A strobe input is provided for each channel. With the strobe in the low level, the receiver is disabled and the outputs are forced to a high level.

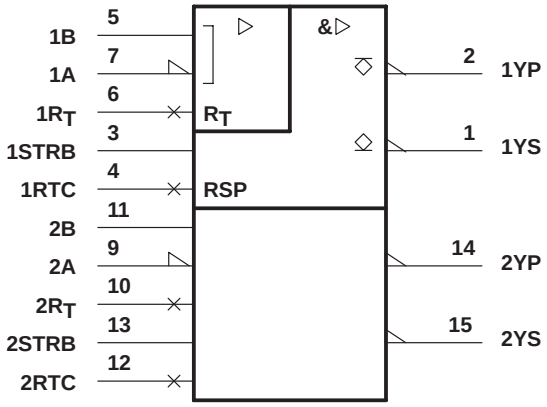
The SN55115 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN75115 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

STRB	DIFF INPUT (A AND B)	OUTPUT (YP AND YS TIED TOGETHER)
L	X	H
H	L	H
H	H	L

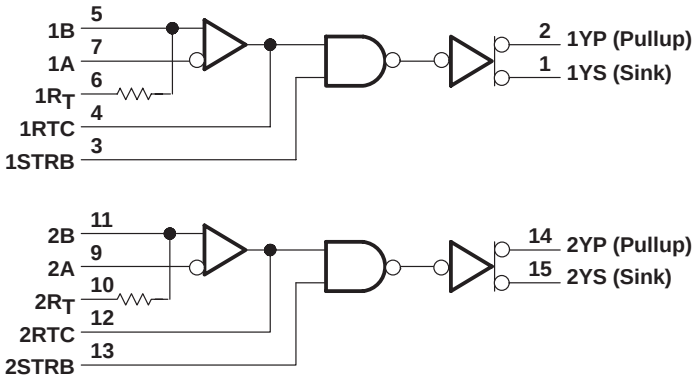
$H = V_I \geq V_{IH}$ min or V_{ID} more positive than V_{T+} max
$L = V_I \leq V_{IL}$ max or V_{ID} more negative than V_{T-} max
X = irrelevant

logic symbol†

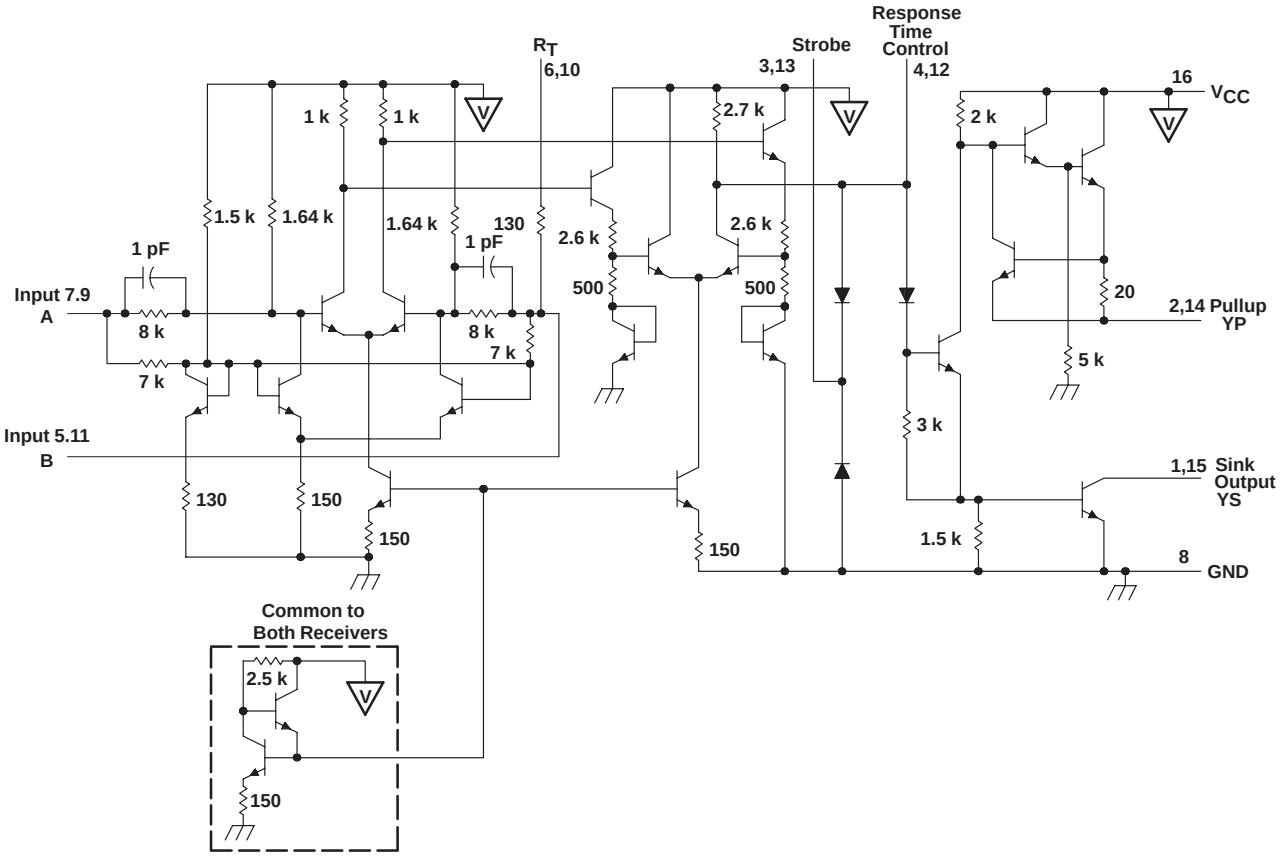


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematic (each receiver)



Resistor values are nominal and in ohms.
Pin numbers shown are for the J, N, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage V_I (A, B, and R_T)	±25 V
Input voltage V_I (STRB)	5.5 V
Off-state voltage applied to open-collector outputs	14 V
Continuous total power dissipation	See Dissipation Rating Table
Storage temperature range, T_{stg}	–65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or W package	300°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: N package	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential input voltage, are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING	$T_A = 125°C$ POWER RATING
FK†	1375 mW	11.0 mW/°C	880 mW	275 mW
J†	1375 mW	11.0 mW/°C	880 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	—
W†	1000 mW	8.0 mW/°C	640 mW	200 mW

† In the FK, J, and W packages, SN55115 chips are either silver glass or alloy mounted. SN75115 chips are glass mounted.

recommended operating conditions

	SN55115			SN75115			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage at STRB, V_{IH}	2.4			2.4			V
Low-level input voltage at STRB, V_{IL}			0.4			0.4	V
High-level output current, I_{OH}			–5			–5	mA
Low-level output current, I_{OL}			15			15	mA
Operating free-air temperature, T_A	–55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		SN55115			SN75115			UNIT
				MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V_{IT+}§	Positive-going threshold voltage	V_O = 0 .4 V, I_{OL} = 15 mA, V_{IC} = 0				500			500	mV
V_{IT-}§	Negative-going threshold voltage	V_O = 2 .4 V, I_{OH} = −5 mA, V_{IC} = 0		−500¶			−500¶			mV
V_{ICR}	Common-mode input voltage range	V_{ID} = ±1 V		+15 to −15	+24 to −19		+15 to −15	+24 to −19		V
V_{OH}	High-level ouput voltage	V_{CC} = MIN, V_{ID} = −0.5 V, I_{OH} = −5 mA	T_A = MIN	2.2			2.4			V
			T_A = 25°C	2.4	3.4		2.4	3.4		
			T_A = MAX	2.4			2.4			
V_{OL}	Low-level output voltage	V_{CC} = MIN, V_{ID} = −0.5 V, I_{OL} = 15 mA			0.22	0.4		0.22	0.45	V
I_{IL}	Low-level input current	V_{CC} = MAX, V_I = 0.4 V, Other input at 5.5 V	T_A = MIN			−0.9			−0.9	mA
			T_A = 25°C		−0.5	−0.7		−0.5	−0.7	
			T_A = MAX			−0.7			−0.7	
I_{SH}	High-level strobe current	V_{CC} = MIN, V_{ID} = −0.5 V, V_{strobe} = 4.5 V	T_A = 25°C			2			5	µA
			T_A = MAX			5			10	
I_{SL}	Low-level strobe current	V_{CC} = MAX, V_{ID} = 0.5 V, V_{strobe} = 0.4 V	T_A = 25°C		−1.15	−2.4		−1.15	−2.4	mA
$I_{(RTC)}$	Response-time-control current	V_{CC} = MAX, V_{ID} = 0.5 V, V_{RC} = 0	T_A = 25°C	−1.2	−3.4		−1.2	−3.4		mA
$I_{O(off)}$	Off-state open-collector output current	V_{CC} = MIN, V_{OH} = 12 V, V_{ID} = −4.5 V	T_A = 25°C			100				µA
			T_A = MAX			200				
		V_{CC} = MIN, V_{OH} = 5.25 V, V_{ID} = −4.75 V	T_A = 25°C						100	
			T_A = MAX						200	
R_T	Line-terminating resistance	V_{CC} = 5 V	T_A = 25°C	77	130	167	74	130	179	Ω
I_{OS}	Supply-circuit output current#	V_{CC} = MAX, V_{ID} = −0.5 V, V_O = 0	T_A = 25°C	−15	−40	−80	−14	−40	−100	mA
I_{CC}	Supply current (both receivers)	V_{CC} = MAX, V_{ID} = 0.5 V, V_{IC} = 0	T_A = 25°C		32	50		32	50	mA

† Unless otherwise noted, V_{strobe} = 2.4 V. All parameters with the exception of off-state open-collector output current are measured with the active pullup connected to the sink output.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C, and V_{IC} = 0.

§ Differential voltages are at the B input terminal with respect to the A input terminal.

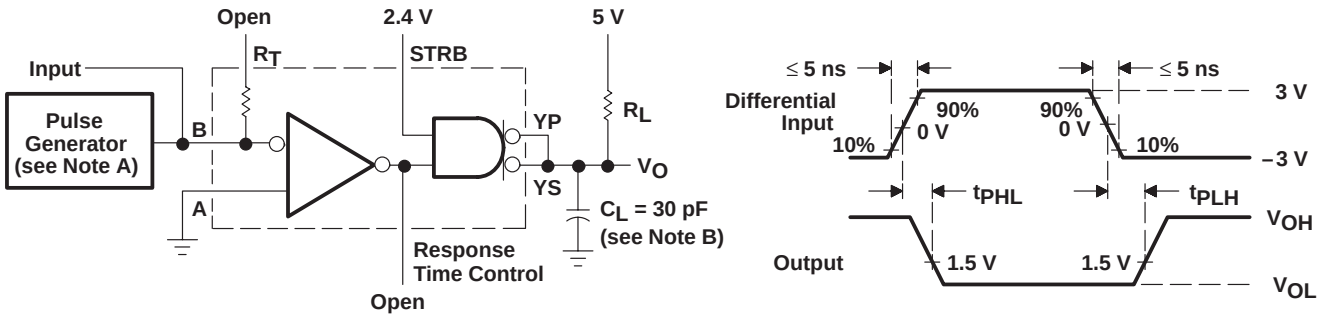
¶ The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for threshold voltages only.

Only one output should be shorted to ground at a time, and duration of the short circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, C_L = 30 pF, T_A = 25°C

PARAMETER		TEST CONDITIONS	SN55115			SN75115			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low-to-high level output	R_L = 3.9 kΩ, See Figure 1		18	50		18	75	ns
t_{PHL}	Propagation delay time, high-to-low level output	R_L = 390 Ω, See Figure 1		20	50		20	75	ns

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT VOLTAGE WAVEFORM

NOTES: A. The pulse generator has the following characteristics: Z_O = 50 Ω, PRR ≤ 500 kHz, t_W ≤ 100 ns, duty cycle = 50%.
B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS†

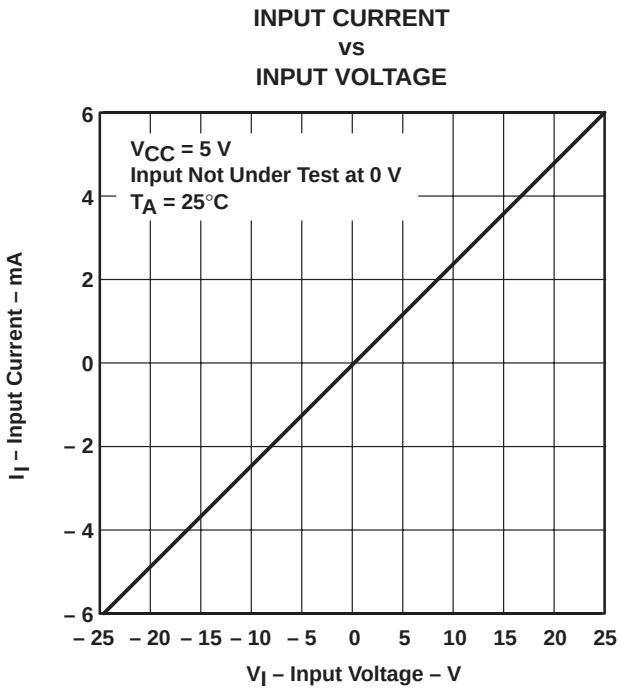


Figure 2

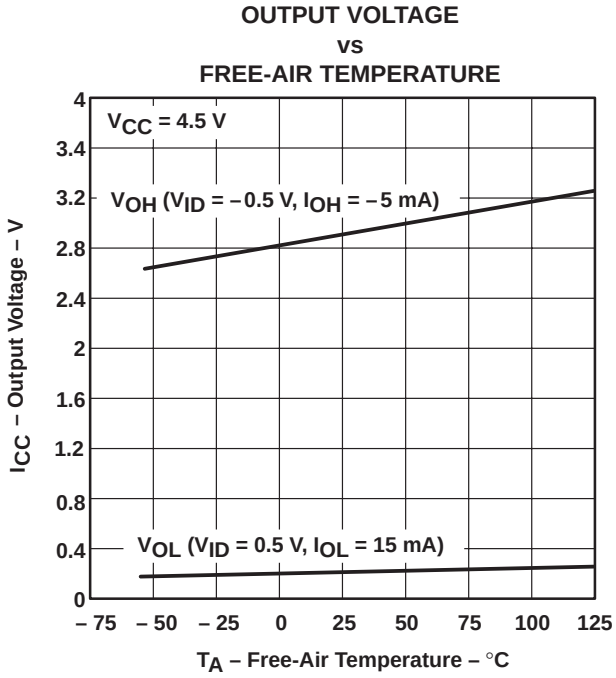


Figure 3

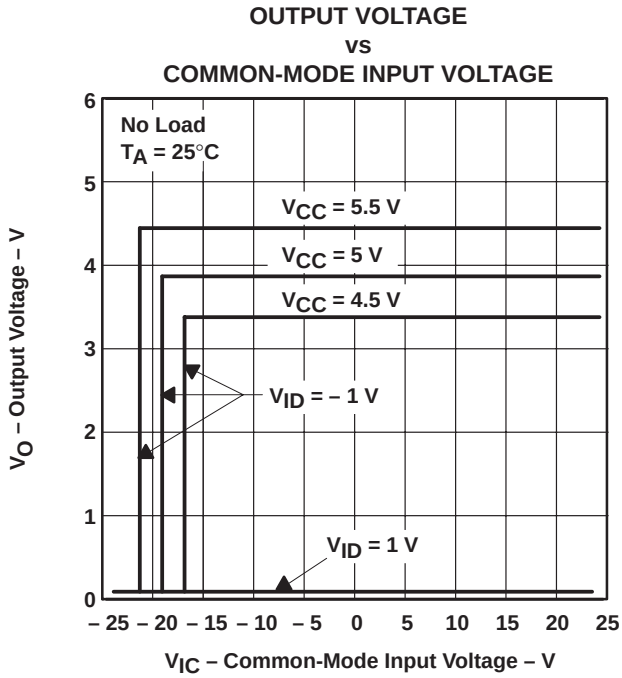


Figure 4

† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55115 circuits only. These parameters were measured with the active pullup connected to the sink output.

TYPICAL CHARACTERISTICS

HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

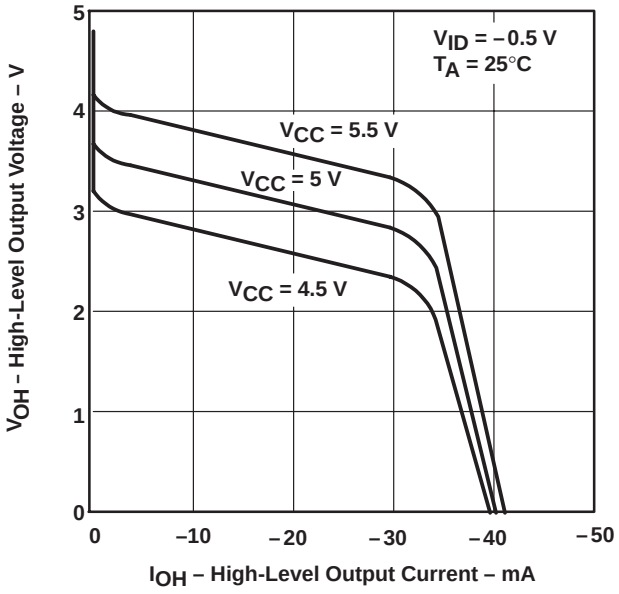


Figure 5

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

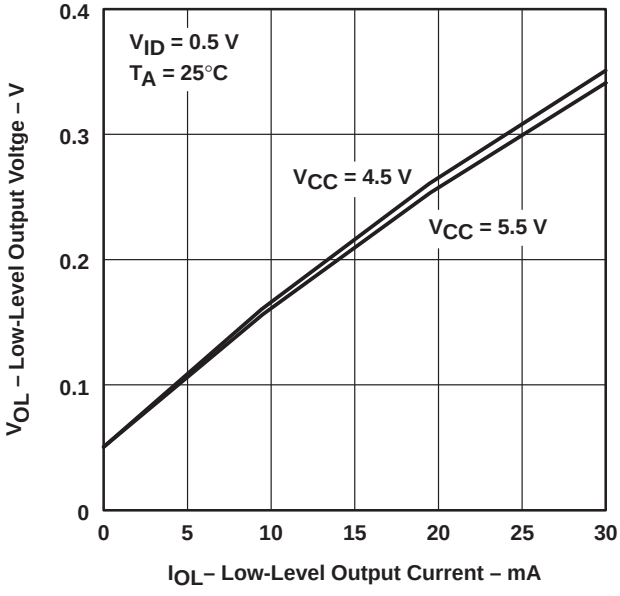


Figure 6

OUTPUT VOLTAGE
vs
DIFFERENTIAL INPUT VOLTAGE

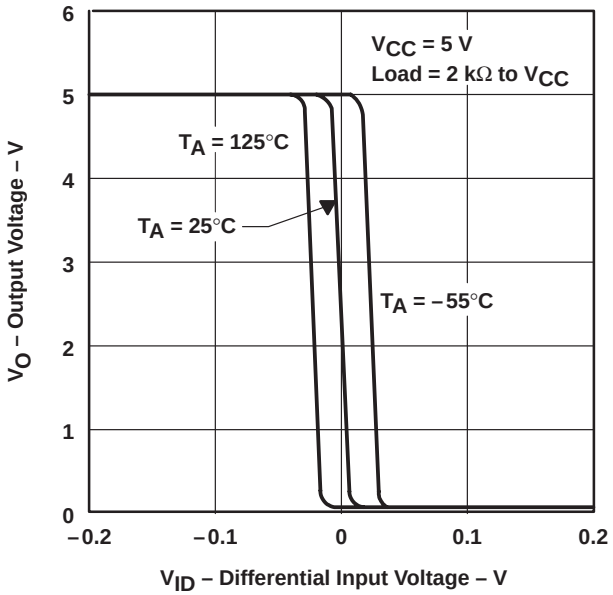


Figure 7

OUTPUT VOLTAGE
vs
DIFFERENTIAL INPUT VOLTAGE

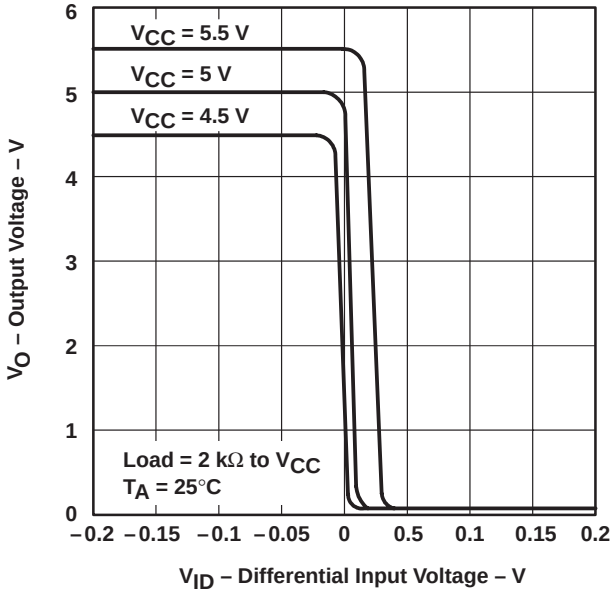


Figure 8

TYPICAL CHARACTERISTICS†

OUTPUT VOLTAGE vs STROBE INPUT VOLTAGE

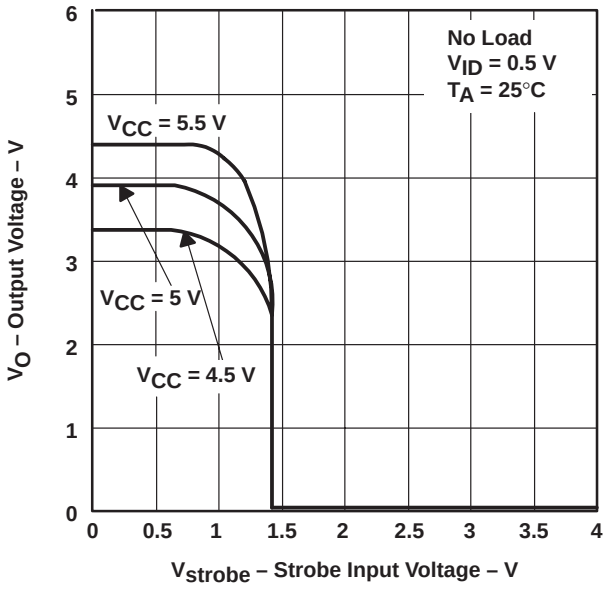


Figure 9

OUTPUT VOLTAGE vs STROBE INPUT VOLTAGE

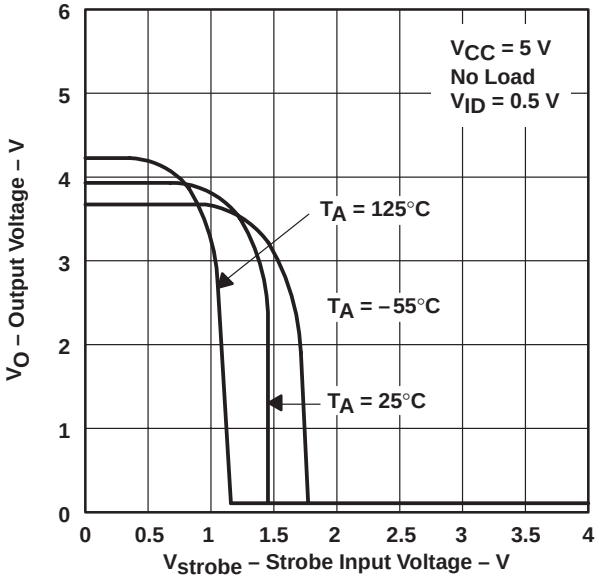


Figure 10

SUPPLY CURRENT (BOTH RECEIVERS) vs SUPPLY VOLTAGE

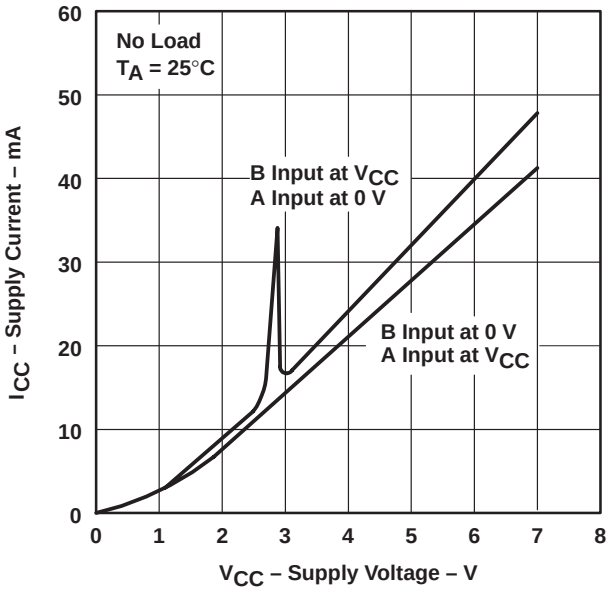


Figure 11

SUPPLY CURRENT (BOTH RECEIVERS) vs FREE-AIR TEMPERATURE

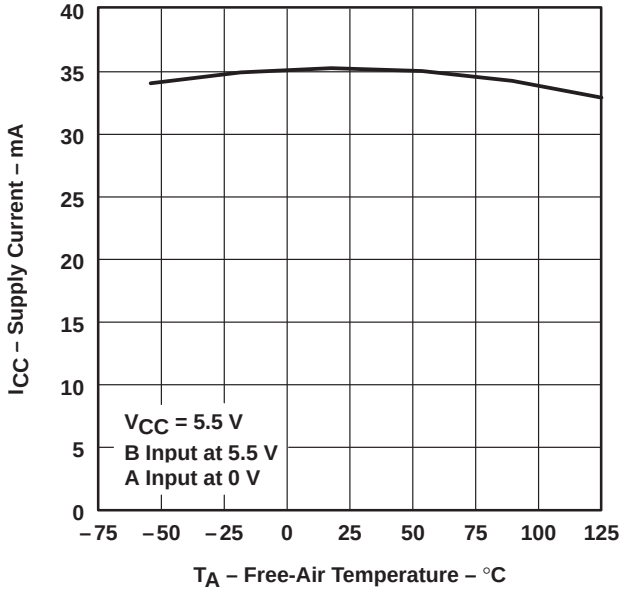


Figure 12

† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55115 circuits only. These parameters were measured with the active pullup connected to the sink output.

TYPICAL CHARACTERISTICS†

PROPAGATION DELAY TIMES vs FREE-AIR TEMPERATURE

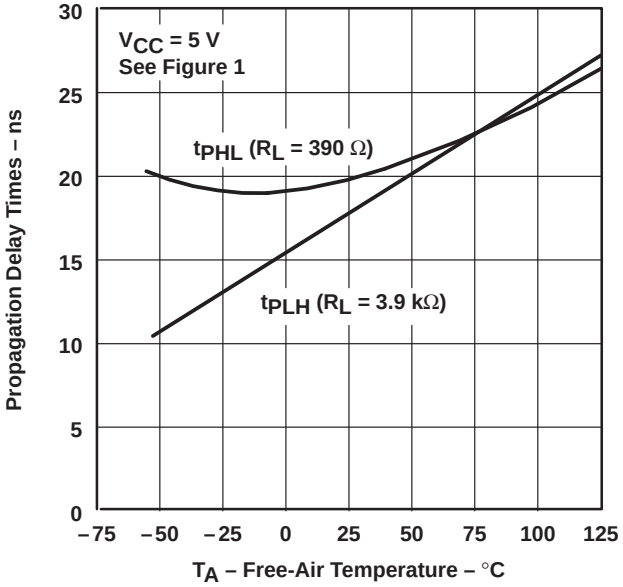


Figure 13

MAXIMUM OPERATING FREQUENCY vs RESPONSE-TIME-CONTROL CAPACITANCE

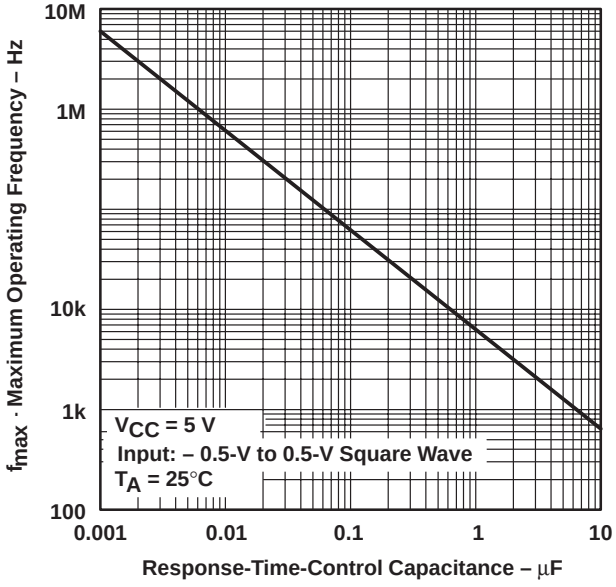
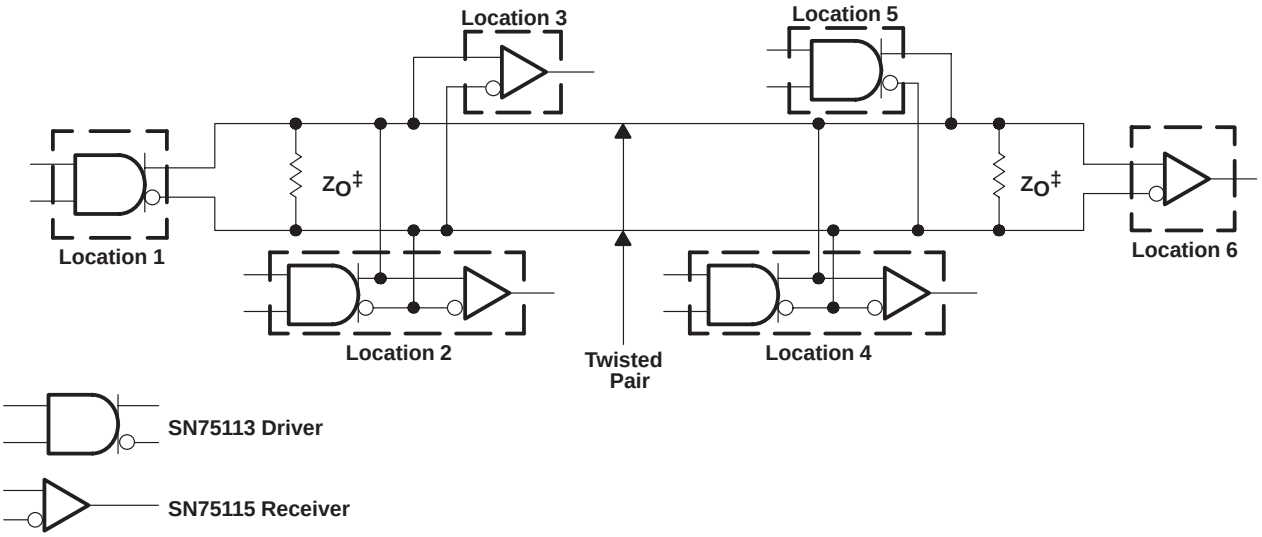


Figure 14

† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55115 circuits only. These parameters were measured with the active pullup connected to the sink output.

APPLICATION INFORMATION



‡ $Z_O = R_T$. A capacitor may be connected in series with Z_O to reduce power dissipation.

Figure 15. Basic Party-Line or Data-Bus Differential Data Transmission

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-88745012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-88745012A SNJ55115FK	Samples
5962-8874501FA	ACTIVE	CFP	W	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8874501FA SNJ55115W	Samples
JM38510/10404BEA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	JM38510/10404BEA	Samples
M38510/10404BEA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	JM38510/10404BEA	Samples
SN55115J	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	SN55115J	Samples
SN75115D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75115	Samples
SN75115DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75115	Samples
SN75115DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75115	Samples
SN75115N	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	0 to 70	SN75115N	Samples
SN75115NE4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	0 to 70	SN75115N	Samples
SN75115NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75115	Samples
SNJ55115FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-88745012A SNJ55115FK	Samples
SNJ55115J	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	SNJ55115J	Samples
SNJ55115W	ACTIVE	CFP	W	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8874501FA SNJ55115W	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF SN55115, SN75115 :

- Catalog: SN75115
- Military: SN55115

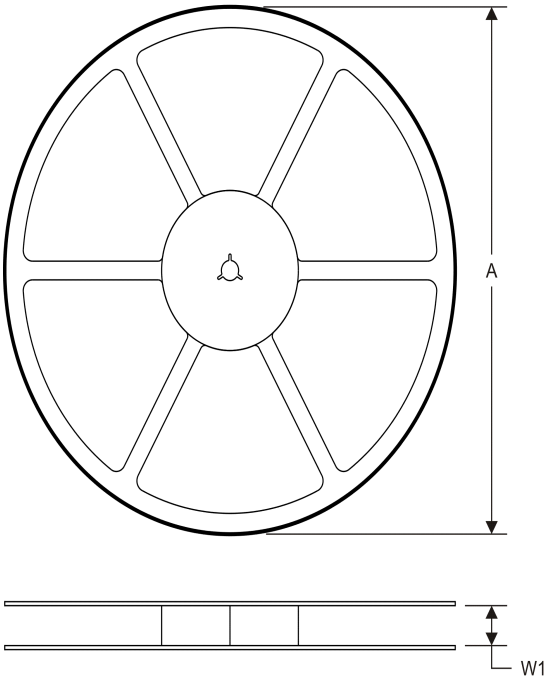
NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

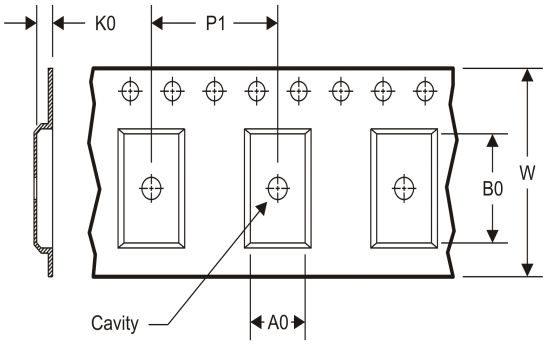
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



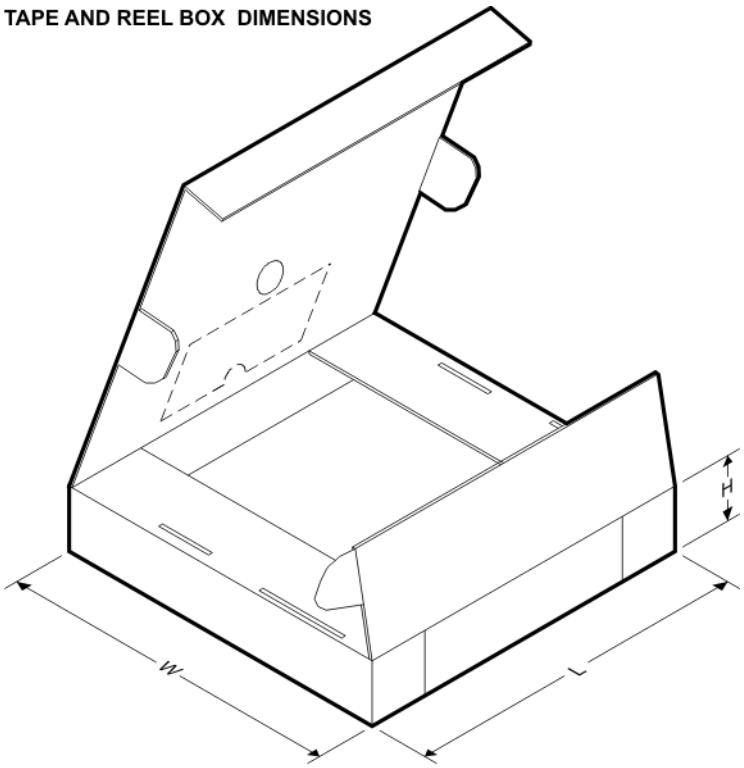
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75115DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75115NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

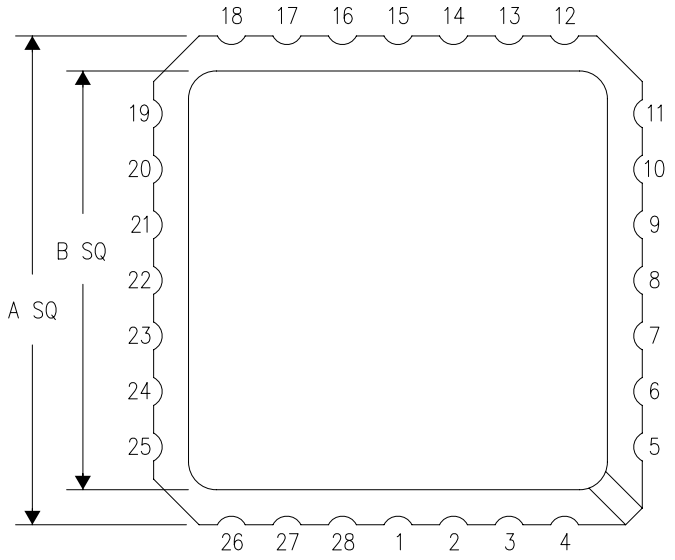


*All dimensions are nominal

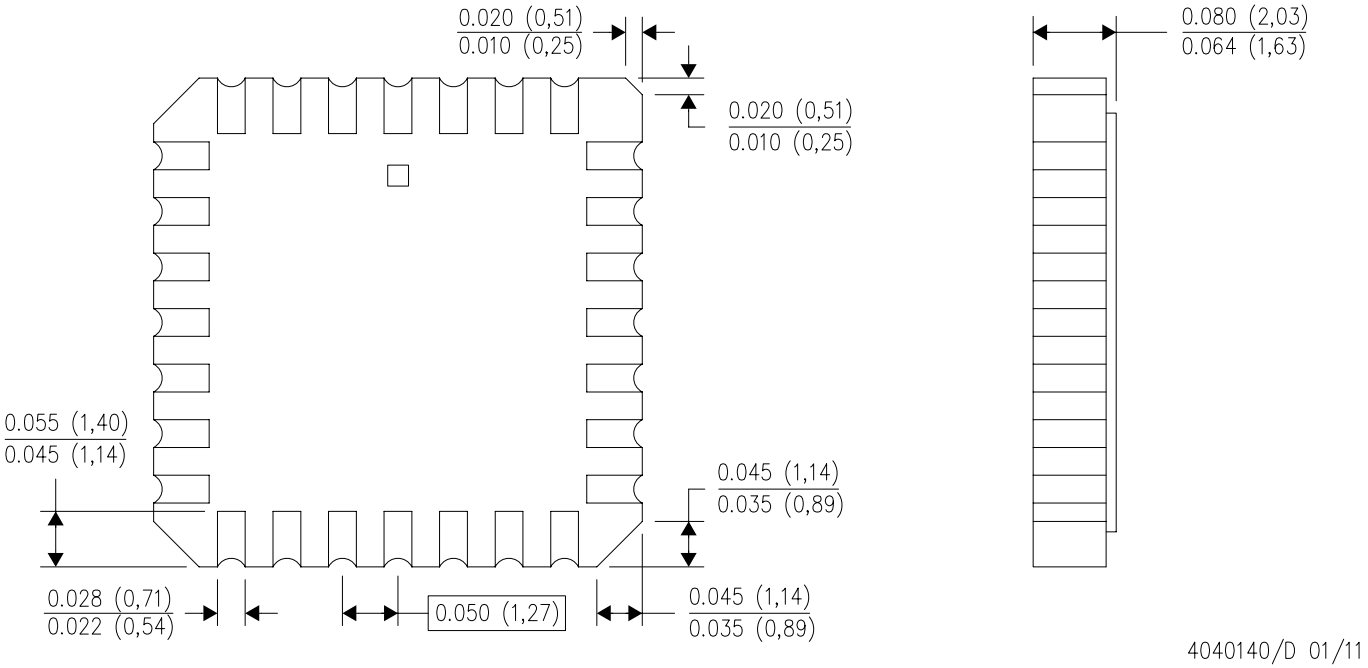
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75115DR	SOIC	D	16	2500	333.2	345.9	28.6
SN75115NSR	SO	NS	16	2000	367.0	367.0	38.0

FK (S–CQCC–N**) LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



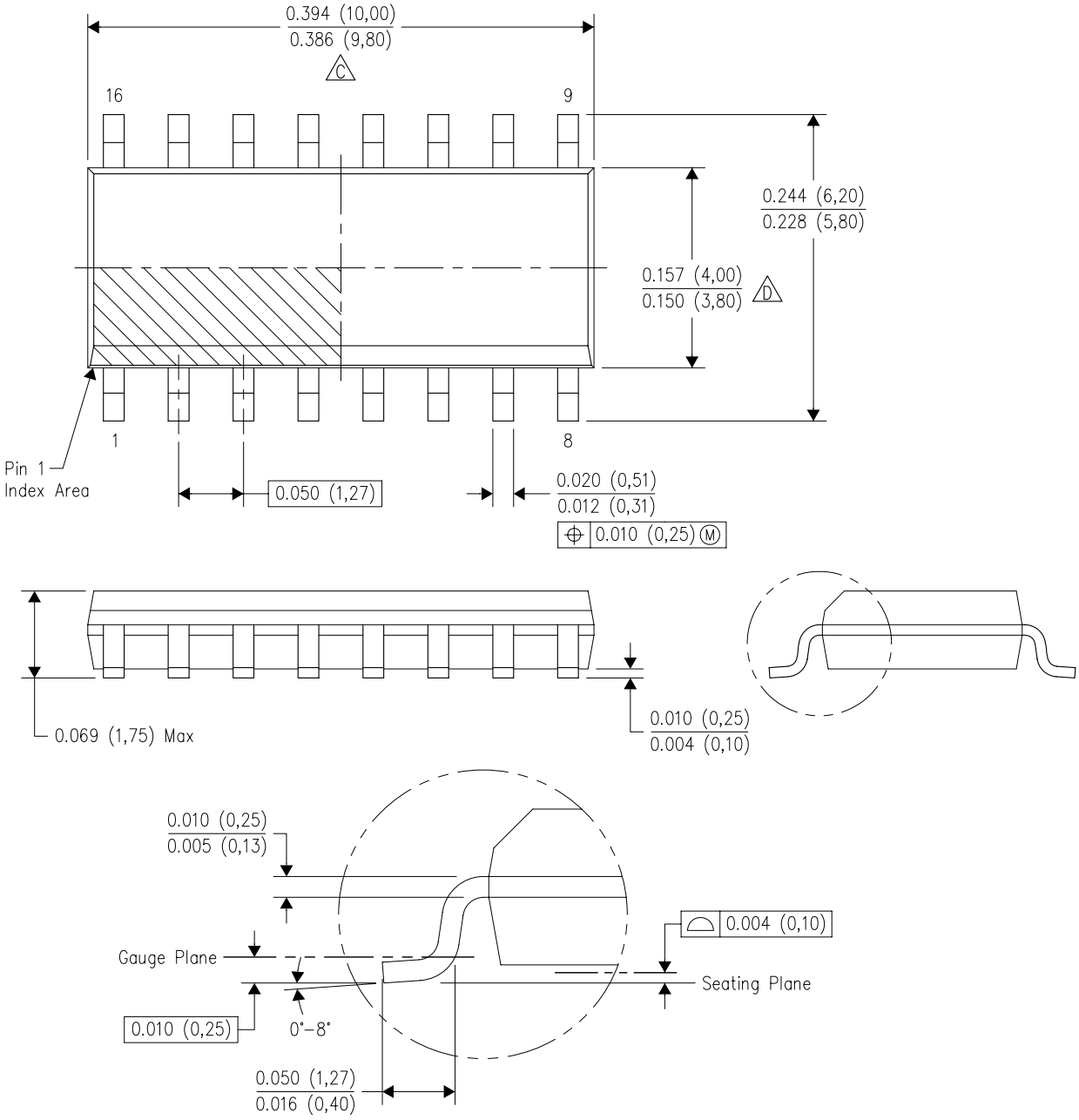
NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)



4040140/D 01/11

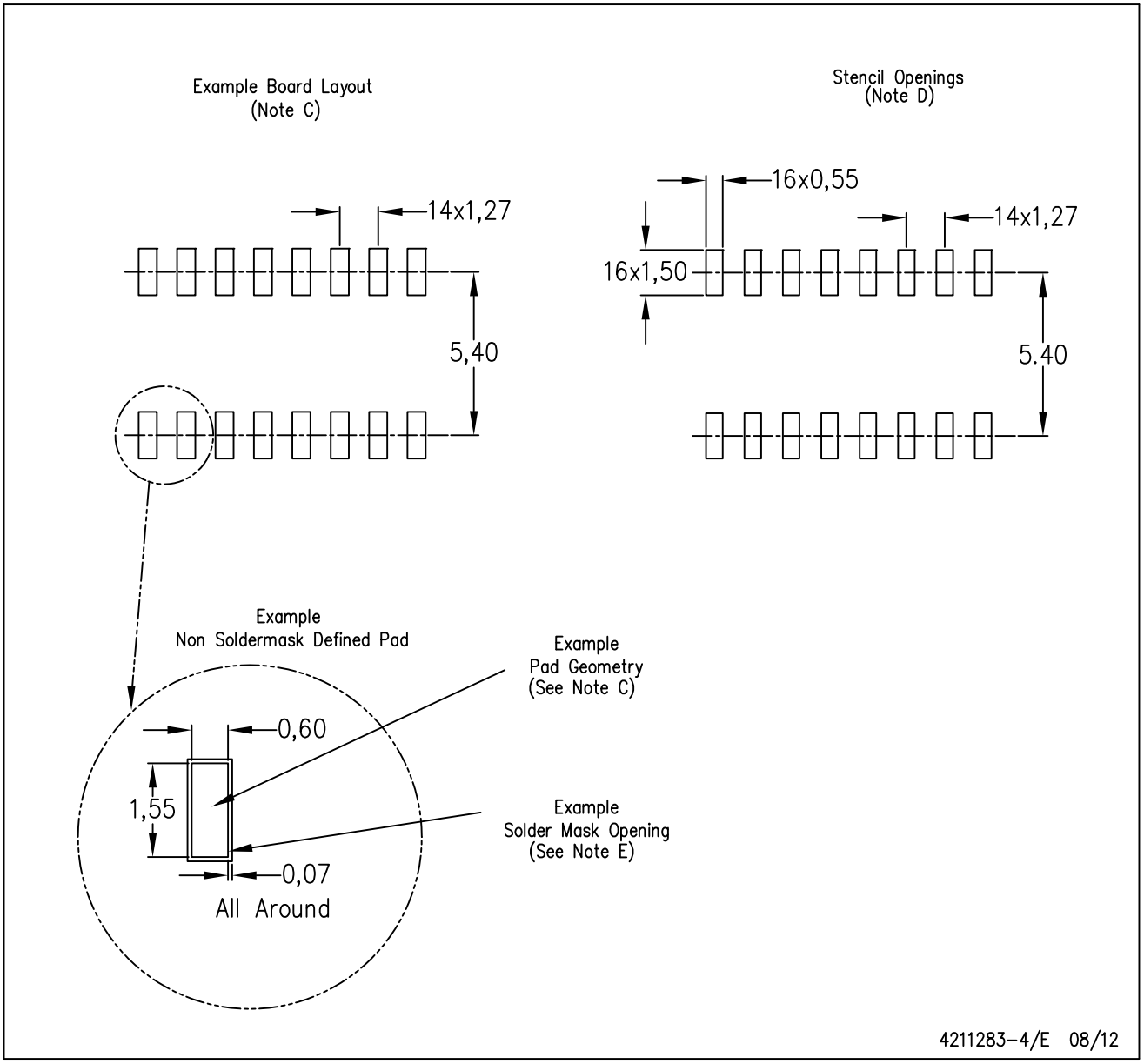
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. Falls within JEDEC MS–004

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE

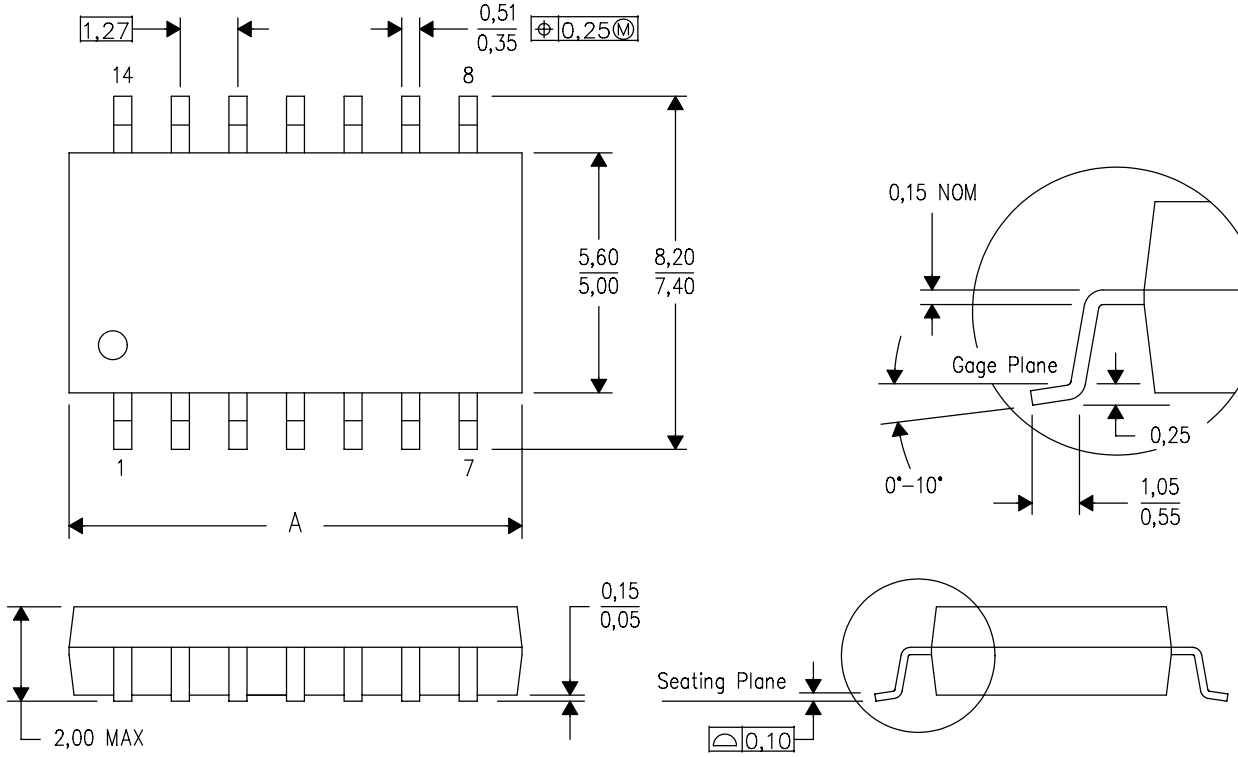


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN

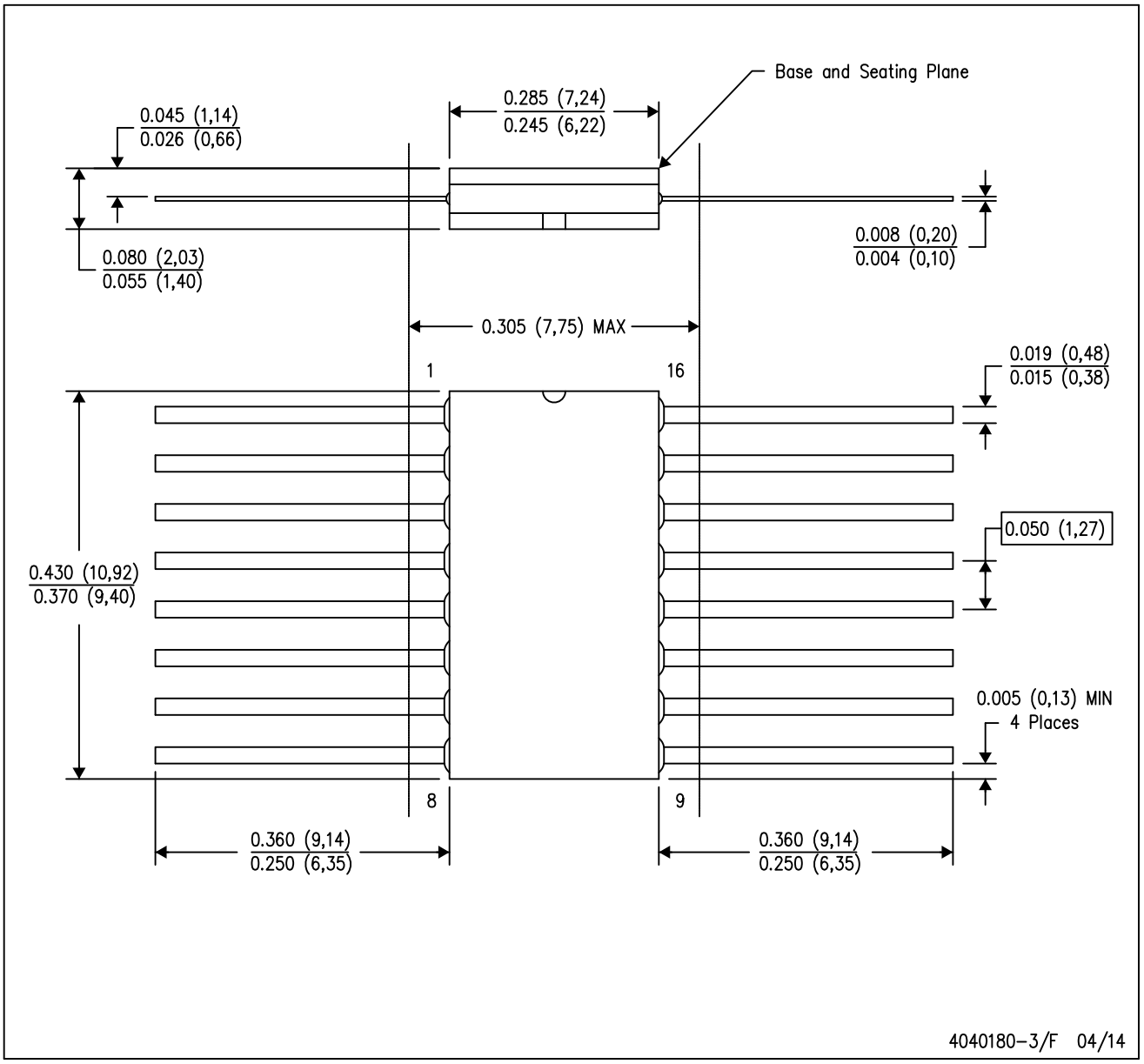


DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

W (R–GDFP–F16) CERAMIC DUAL FLATPACK

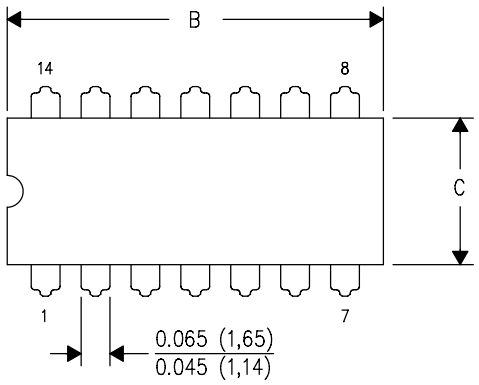


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only.
E. Falls within MIL STD 1835 GDFP2–F16

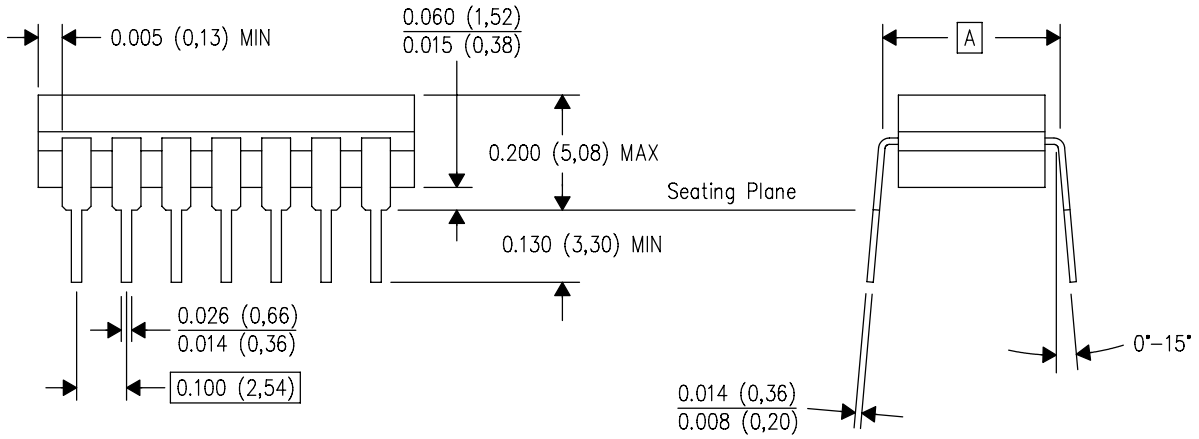
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



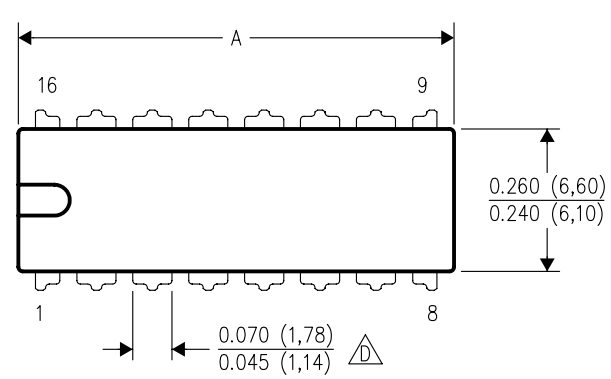
4040083/F 03/03

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

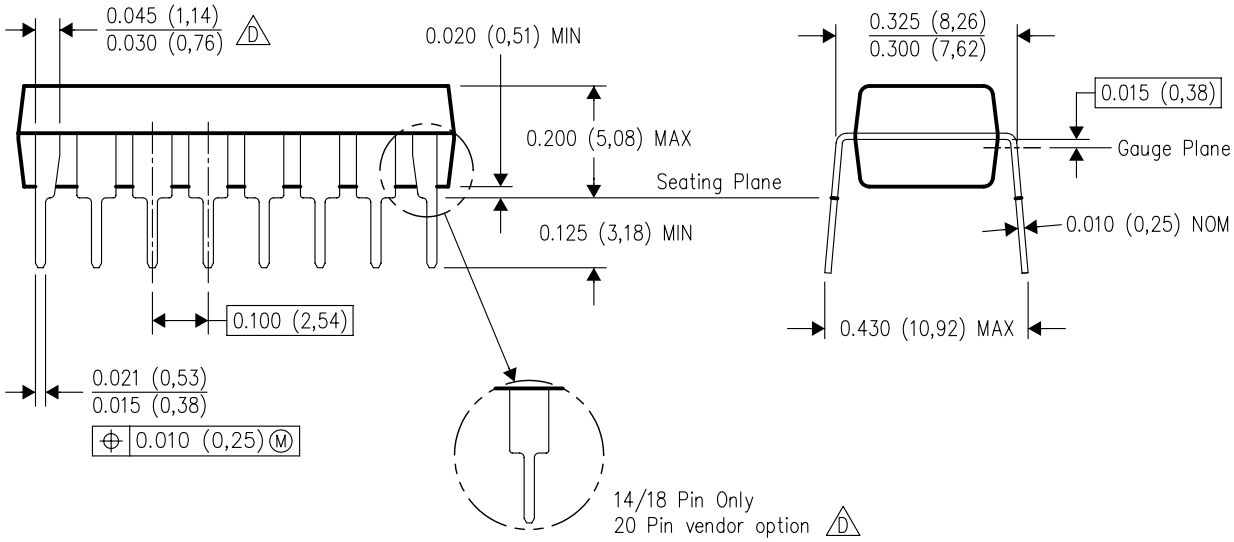
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

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Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265